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Dependence of the superconducting transition temperature of single and polycrystalline MgB₂ on hydrostatic pressure

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Abstract

The dependence of T_c for MgB₂ on purely hydrostatic or nearly hydrostatic pressure has been determined to 29 GPa for single-crystalline and to 32 GPa for polycrystalline samples, and found to be in good agreement. T_c decreases from 39 K at ambient pressure to 15 K at 32 GPa with an initial slope $dT_c/dP \simeq -1.11(2)$ K/GPa. Evidence is presented that the differing values of dT_c/dP reported in the literature may result primarily from shear-stress effects in nonhydrostatic pressure media rather than from differences in the samples. Although comparison of these results with theory supports phonon-mediated superconductivity, a critical test of theory must await calculations based on the solution of the anisotropic Eliashberg equations as a function of the lattice parameters.

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1. Introduction

In spite of considerable efforts during the 20 months since the discovery of superconductivity in MgB₂ at 39 K [1], the search for a further binary compound with a higher value of T_c has yet to bear fruit [2]. In contrast, the high- T_c oxide Y–Ba–Cu–O ($T_c \approx 92$ K) was synthesized [3] only a few weeks after the landmark discovery of superconductivity near 35 K in La–Ba–Cu–O [4]. Progress with the binary compounds may have to wait until

we first reach a clear understanding of MgB₂'s extraordinary superconducting and normal-state properties, most of which are highly anisotropic. The compressibility, for example, is 64% larger along the c -axis than along the a -direction [5]. Under c -axis compression the electronic density of states $N(E_F)$ is predicted to decrease much more rapidly ($\sim 0.6\%/GPa$) than under hydrostatic compression ($\sim 0.1\%/GPa$) [6], the σ band shifting downward and the hole number in the σ band decreasing [7]. The anisotropy in the upper critical field H_{c2} increases strongly with decreasing temperature [8,9], approaching a value near 7 at 0 K [8]. A large number of experiments point to the existence of at least two superconducting energy

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gaps [10] which are predicted [11–13] to open up on different parts of the anisotropic Fermi surface. Gonnelli et al. [14] have very recently provided direct evidence for two-band superconductivity in MgB_2 where the temperature-dependence of the distinct gaps originating from the σ and π bands were measured using point-contact spectroscopy on single-crystals.

The existence of multiple gaps and the highly anisotropic electronic and lattice-vibration properties of MgB_2 have recently prompted Choi et al. [13] to attempt the solution of the fully anisotropic Eliashberg equations, including the anharmonicity of the important E_{2g} phonon modes. A comparison of their calculation with experiment has yielded promising results [12,13]. A critical test of their approach would be provided by extending their calculation to reduced lattice parameters, allowing a direct comparison with the results of high-pressure experiments.

Following the discovery of a new superconductor, high-pressure studies are often among the first to be carried out. The reason for this is that the magnitude and sign of dT_c/dP help guide the materials scientist how to best modify the superconductor to raise T_c at ambient pressure, a case in point being the discovery of Y–Ba–Cu–O [3]. In addition, the high-pressure technique, sometimes in conjunction with high temperatures, is also invaluable to: (1) create new superconductors (e.g. sulfur [15] or oxygen [16] which metallize at Mbar pressures); (2) vary the properties of known superconductors (e.g. polycrystalline MgB_2 [17] or the synthesis of MgB_2 single-crystals [18–20]); (3) induce structural phase transitions (e.g. in Ba, As, Bi, Sn, Ga and Tl [21]); and, finally, (4) vary the lattice parameters to help identify the pairing mechanism and critically test theoretical models. Unfortunately, this final application has been traditionally underutilized by theorists.

Hydrostatic or uniaxial pressure experiments on single-crystals determine the dependence of a given property solely on the lattice parameters. Most high-pressure experiments, however, are carried out under nonhydrostatic conditions which subject the sample to a distribution of unspecified shear stresses. These shear stresses may be large enough to plastically deform the sample, resulting in last-

ing distortions and lattice defects. The pressure dependence of T_c may thus depend on whether the pressure medium is hydrostatic or not, particularly in elastically anisotropic materials like quasi-1D and -2D organic superconductors [22] or high- T_c oxides [23]. Studies on single-crystals are of particular value since strain effects from grain boundaries in polycrystalline materials are avoided.

Several studies of the dependence of T_c on pressure for polycrystalline MgB_2 were carried out shortly after the discovery of its superconductivity [24–27]. Using solid steatite pressure medium to 20 GPa, Monteverde et al. [24] reported that T_c decreased under pressure at different initial rates (–0.35 to –0.8 K/GPa) for each of the four samples studied. On the other hand, in an experiment in fluid Fluorinert to ~ 1.7 GPa, Lorenz et al. [25] and Saito et al. [26] found $dT_c/dP \simeq -1.6$ and -1.9 K/GPa, respectively. The first truly hydrostatic measurement of $T_c(P)$ was carried out by our group to 0.7 GPa using He gas on an isotopically pure (^{11}B) sample, revealing that T_c decreases reversibly under hydrostatic pressure at the rate $dT_c/dP \simeq -1.11(2)$ K/GPa [27]; later work on isotopically pure ^{10}B and ^{11}B samples yielded dependences between $-1.09(4)$ and $-1.12(3)$ K/GPa [28]. In further He-gas studies, Lorenz et al. [29] and Schlachter et al. [30] obtained -1.07 and -1.13 K/GPa, respectively. Experiments utilizing fluid pressure media were carried out by Razavi et al. ($-1.18(6)$ K/GPa) [31], Choi et al. (-1.36 K/GPa) [32], and Kazakov et al. (-1.5 K/GPa) [33]. The first high-pressure measurements on a single-crystal were carried out by Masui et al. [34] using Fluorinert, yielding $dT_c/dP \simeq -2.0$ K/GPa. In the above experiments the values of dT_c/dP reported are seen to differ by more than a factor of two. Experiments to much higher pressures have been carried out by several groups and will be discussed below. The results of all known dT_c/dP measurements on MgB_2 are summarized in Table 1.

In this paper we provide evidence that the variation in the reported $T_c(P)$ dependences for MgB_2 is primarily a result of shear stresses exerted by the solidified pressure media on the sample. From recent measurements on high quality single-crystalline and polycrystalline samples we con-

Table 1
Summary of available high-pressure $T_c(P)$ data on MgB₂ single-crystals (first 5 rows) and polycrystals (remaining rows)

$T_c(0)$ (K)	$(dT_c/dP)_0$ (K/GPa)	P^{\max} (GPa)	Measurement	Pressure medium	Reference
38.24	-1.10(3)	0.63, 23	χ_{ac} , “B” crystal	Helium	This paper
38.27	-1.14(3)	0.61	χ_{ac} , “B” crystal	Helium	This paper
37.16	-1.17(4)	0.4	χ_{ac} , “A” crystal	Helium	This paper
37.88	-1.12(3)	0.58	χ_{ac} , “A” crystal	Helium	This paper
38.0	-2.0	1.4	ρ , crystal	Fluorinert	[34]
39.1	-1.11(2)	0.66	χ_{ac} , ¹¹ B	Helium	[27]
39.1	-1.09(4)	0.63	χ_{ac} , ¹¹ B	Helium	[28]
39.2	-1.11(3)	0.61	χ_{ac} , ¹¹ B	Helium	[28]
40.5	-1.12(3)	0.64	χ_{ac} , ¹⁰ B	Helium	[28]
37.5	-1.13	0.4	χ_{ac}	Helium	[30]
39.2	-1.07	0.84	χ_{ac}	Helium	[29]
37.4	-1.45	0.84	χ_{ac}	Helium	[29]
37.3	-1.2	0.6	χ_{ac}	Helium	[44]
39.1	-1.1	32.3	χ_{ac} , ¹¹ B	Helium	This paper
40.2	-1.1	33	χ_{ac}^{mod} , ¹¹ B	Helium	[39]
39.2	-1.1	44	χ_{ac}^{mod} , ¹⁰ B	Helium	[39]
39.1	-1.6	15	χ_{ac}^{mod} , ¹¹ B	Fluorinert	This paper
37.4	-1.6	1.84	χ_{ac}	Fluorinert	[25]
37.3	-2	28	χ_{ac}	4:1 methanol/ethanol	[41]
38.2	-1.36	1.46	ρ	1:1 daphne/kerosene	[32]
37.5	-1.9	1.35	ρ	Fluorinert	[26]
38.3	-1.5(1)	1.1	χ_{dc}	Kerosene/mineral oil	[33]
39.6	-1.03	9	ρ	Fluorinert	[40]
38	-1.18(6)	0.8	χ_{dc}	Silicon oil	[31]
37.5	-1.6 (P↑)	7.6	χ_{ac}	NaF	[30]
37.5	-1.13 (P↓)	7.6	χ_{ac}	NaF	[30]
39	-1.20(9)	11	ρ	Steatite	[31]
~35	-0.35 to -0.8	33	ρ	Steatite	[24,42]

T_c values are at ambient pressure from the superconducting midpoint in the ac susceptibility χ_{ac} and electrical resistivity ρ measurements; Struzhkin et al. [39] use a double-modulation technique χ_{ac}^{mod} which is believed to give the superconducting onset. $(dT_c/dP)_0$ is the initial pressure derivative. P^{\max} (GPa) is the maximum pressure reached in the experiment. Unless otherwise specified, samples with the natural boron isotopic abundance ^{10,81}B are studied. Arrows indicate increasing (↑) or decreasing (↓) pressure.

clude that the initial dependence of the transition temperature on purely hydrostatic pressure is given by $dT_c/dP \simeq -1.11(2)$ K/GPa under nearly hydrostatic (dense He) pressures to 32 GPa ($V/V_0 \simeq 0.855$), we find T_c to decrease monotonically from ~39 to 15 K. Although these results appear consistent with phonon-mediated superconductivity in MgB₂, a quantitative check must await comparison with calculations based on the fully anisotropic Eliashberg equations.

2. Experimental

A wide variety of high-pressure techniques with many different pressure media have been used to

study the dependence of T_c on pressure [35]. All techniques discussed below have been used at some time by our group.

Perhaps the most widely used technique in the pressure range 1–2 GPa is a piston-cylinder cell in which two pistons compress a Teflon bucket containing the sample immersed in a fluid pressure medium such as Fluorinert, n-pentane/isopentane, or silicon oil. For studies to higher pressure a diamond-anvil-cell (DAC) may be used with a 4:1 methanol:ethanol mixture as pressure medium since this mixture remains fluid to approximately 10 GPa at ambient temperature. All these fluid pressure media freeze upon cooling and subject the immersed sample to shear stresses of varying strength which depend on the pressure medium

used, the details of the pressure technique, and the rate at which the pressure cell is cooled, among other factors.

The only pressure medium that remains fluid under high pressure near 40 K, where MgB_2 superconducts, is helium and thus only high-pressure experiments on MgB_2 in liquid helium are able to determine the dependence of T_c on purely hydrostatic pressure. At pressures above 0.5 GPa, even helium is frozen below 39 K, but the pressure is still very nearly hydrostatic since solid helium is the softest solid known; in addition, if the proper cooling procedure is followed, a single-crystal of helium can be grown around the sample, resulting in negligible shear stresses which permit even de Haas van Alphen measurements on single-crystals at very low temperatures [36]. High-pressure studies in liquid helium are thus the measurements-of-choice for exacting quantitative studies of the properties of solids under high-pressure conditions.

At the other end of the spectrum, in some high-pressure techniques solid pressure media (e.g. steatite, NaCl or NaF) are used [35]. With a solid pressure medium, the application of pressure may subject the sample to relatively large shear stresses, possibly strong enough to plastically deform the sample or even crush it, thus introducing a large number of lattice defects. The magnitude and direction of the shear stresses depend, among other things, on the pressure medium used, the temperature at which the pressure is changed, the pressure range, and whether the ring containing the solid pressure medium is supported by a “belt” or not. With this so-called “quasi-hydrostatic” technique T_c may not be a reversible function of pressure. For these reasons high-pressure techniques using solid pressure media should be avoided in quantitative studies, particularly when studying elastically anisotropic materials such as the high- T_c oxides [23], organic superconductors [22], and MgB_2 .

In the present experiments, dense helium is used as pressure medium both in a He-gas pressure cell to 0.7 GPa and in a DAC to over 30 GPa. The pressure in the cell is measured at temperatures within a few degrees of the transition temperature T_c ; the superconducting transition is detected in a

sensitive ac susceptibility measurement. Details of these pressure techniques have been published elsewhere [37]. Isotopically pure polycrystalline MgB_2 samples were synthesized at the Argonne National Labs [5,38]. Single-crystals were grown at the Superconductivity Research Laboratory (IS-TEC) in Tokyo, Japan [18]; following the crystal growth at elevated temperatures, “type A” (“type B”) crystals were quenched (slow cooled). The dimensions of the crystals studied in the He-gas cell were approximately $0.15 \times 0.4 \times 0.03 \text{ mm}^3$ and in the DAC $0.09 \times 0.09 \times 0.03 \text{ mm}^3$.

3. Results of experiment

In Figs. 1–3 we show the results of our measurements of the pressure dependence of T_c on MgB_2 single-crystals. The midpoint of the superconducting transition in the real part of the ac susceptibility χ' is used to define T_c ,¹ as seen in Fig. 1. The two “type B” crystals have higher values of T_c (~ 38.2 K) than the “type A” crystals (37.2 and 37.9 K). For both “type A” and “type B” crystals T_c is seen in Fig. 2 to decrease reversibly and linearly with hydrostatic (He-gas) pressure to ~ 0.5 GPa. As with the polycrystalline samples, the same $T_c(P)$ dependence is obtained whether the pressure is changed at low temperatures or at room temperature. As seen in Table 1, the pressure dependence of T_c in the He-gas experiments is very nearly the same whether MgB_2 is in single or polycrystalline form.

In Fig. 3 we extend the He-gas results on the same “type B” single crystal² to much higher pressures (~ 29 GPa) using a He-loaded DAC. The initial $T_c(P)$ dependence agrees well with the data

¹ We use the midpoint of the superconducting transition in χ' to define T_c rather than the onset. Since the transition broadens somewhat at higher pressures due to pressure inhomogeneity and/or strain effects from the solid He pressure medium, the superconducting midpoint, rather than the onset, would be expected to give a temperature closer to the average in the sample.

² The small “type B” crystal ($\sim 0.09 \times 0.09 \times 0.03 \text{ mm}^3$) used in the DAC experiment was actually cut-off from the larger crystal used to obtain the He-gas data (●) in Fig. 2.

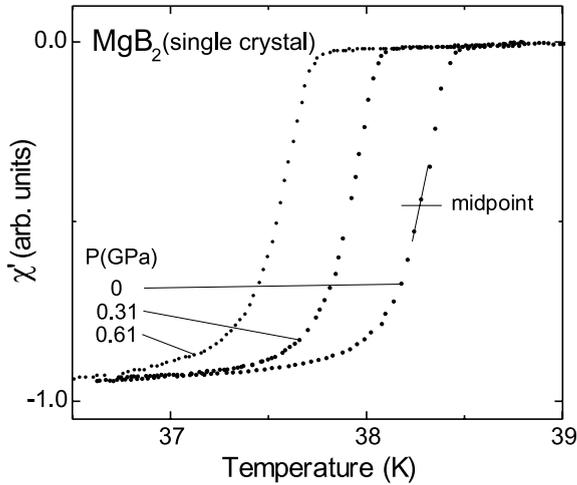


Fig. 1. Real part of the ac susceptibility χ' (1023 Hz, 1 Oe (rms)) versus temperature for a “type B” MgB_2 single-crystal at three different pressures. The position of the superconducting midpoint is indicated for ambient pressure data.

in Fig. 2, showing a positive curvature at higher pressures. As seen in Fig. 3, this curvature is removed if T_c is plotted versus the relative unit-cell volume V/V_0 .³ The linearity of the T_c versus V/V_0 data over such a wide range of pressure is remarkable.

In Fig. 4 are shown our $T_c(P)$ data on an isotopically pure ^{11}B polycrystalline sample to 32 GPa from three separate experiments in a He-loaded DAC;⁴ the sample used is from the same synthesis batch as in our earlier He-gas studies to 0.7 GPa [27]. T_c decreases monotonically and reversibly with pressure from ~ 39 K at ambient pressure to ~ 15 K at 32 GPa. The initial slope, $dT_c/dP \simeq -1.1$ K/GPa, is the same as in the He-gas data. As will be discussed below (see Fig. 7), the single-crystal and polycrystalline data are in good agreement.

The only other $T_c(P)$ measurements on polycrystalline MgB_2 to very high pressures using dense He as pressure medium were carried out by

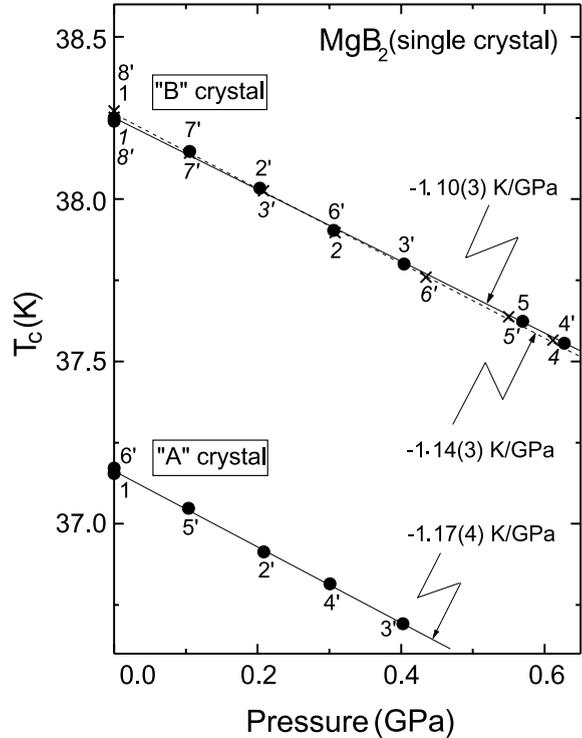


Fig. 2. Dependence of the superconducting transition temperature of one “type A” (●) and two “type B” (●,×) MgB_2 single-crystals on hydrostatic He-gas pressure. Numbers give order of measurement. Pressure was normally changed at room temperature; for data with primed numbers the pressure was changed at low temperatures (~ 50 K). Solid and dashed straight lines are guides to the eye.

Struzhkin et al. [39] and are included in Fig. 4 for the ^{11}B isotope; these authors use a double-modulation ac susceptibility technique which determines the superconducting onset rather than the superconducting midpoint. As seen in Fig. 4, the agreement with our data is remarkably good to 20 GPa, but begins to deviate at higher pressures. Parallel studies by the same authors [39] to 44 GPa in dense He on a ^{10}B isotopic sample yield a similar $T_c(P)$ dependence which lies ~ 1 K above their ^{11}B data below 20 GPa, but gradually merges at higher pressures. Unlike our data in Figs. 3 and 4, where T_c is seen to be a linear function of V/V_0 , the data of Struzhkin et al. [39] show a break in slope dT_c/dV near 15–20 GPa. For a full discussion of the latter data see the paper by Goncharov and Struzhkin in this special edition.

³ We use the Murnaghan equation-of-state $V/V_0 = [1 + B'P/B]^{-1/B'}$ with the value $B = 147.2$ GPa from Ref. [5] and the canonical value $B' \equiv dB/dP = 4$ supported by the $V(P)$ data to 40 GPa [42] and a recent calculation [55].

⁴ The $T_c(P)$ data to 24 GPa are taken from Ref. [28] after correcting the pressure values for a spectrometer miscalibration.

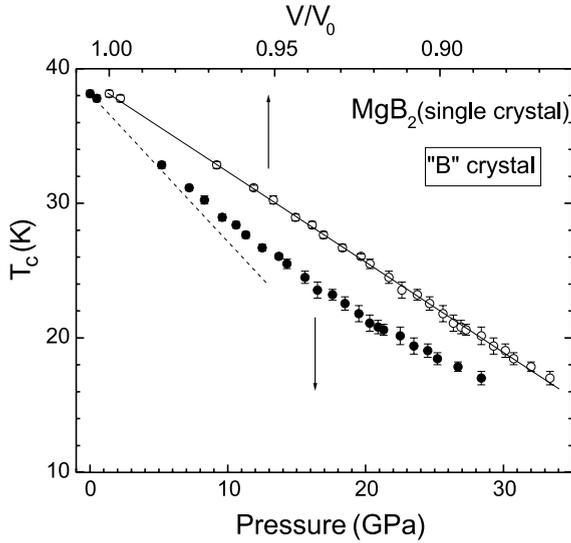


Fig. 3. Dependence of the superconducting transition temperature of “type B” MgB_2 single-crystal on nearly hydrostatic pressure in a He-loaded DAC. All data taken in order of increasing pressure, where pressure was only changed at ambient temperature. T_c is determined from the midpoint of the superconducting transition in the temperature-dependent ac susceptibility χ' (1003 Hz, 3 Oe (rms)). Dashed line gives slope $dT_c/dP \approx -1.10$ K/GPa of He-gas measurement on same crystal (Fig. 2). The “error bars” give the temperatures of the onset and end of the superconducting transition; note that the transition broadens for $P \geq 14$ GPa. T_c versus relative volume V/V_0 is also shown; straight solid line is guide to the eye.

Non-He-gas studies to very high pressures include those of Tang et al. [40] to 9 GPa using a cubic-anvil cell with Fluorinert pressure medium; the $T_c(P)$ dependence is in good agreement with that in Fig. 4. However, in DAC studies using methanol–ethanol, Tissen et al. [41] found a much larger initial slope ($dT_c/dP \approx -2$ K/GPa) accompanied by a relatively large drop in T_c to approximately 6 K at 28 GPa; these authors interpret a break in slope dT_c/dP near 10 GPa as evidence for a topological transition. We note that the present $T_c(P)$ data lie 1–2 K below those of Razavi et al. [31] to 11 GPa obtained using steatite pressure medium. In further DAC measurements using steatite Bordet et al. [42] and Monteverde et al. [24] report $T_c(P)$ dependences for four different samples which generally lie well above those in the present measurement.

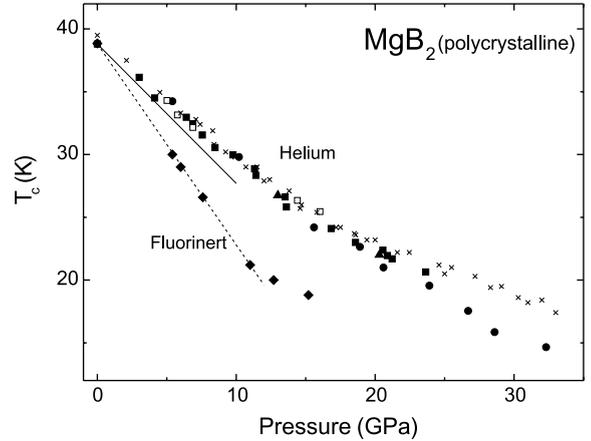


Fig. 4. Dependence of the superconducting transition temperature of isotopically pure ^{11}B polycrystalline MgB_2 on nearly hydrostatic pressure in He-loaded DAC measurements: three different experiments (\bullet , \blacksquare , \square , \blacktriangle), closed symbols (increasing pressure), open symbols (decreasing pressure); measurements from Struzhkin et al. [39] (\times). Measurements in our DAC on same sample with Fluorinert pressure medium (\blacklozenge) are also shown; solid and dashed lines gives slopes (-1.11 K/GPa) and (-1.6 K/GPa) from He-gas [27] and Fluorinert data, respectively, on same sample.

4. Discussion

4.1. Intrinsic dependence of T_c on pressure

Before attempting a quantitative analysis of the present data, we would like to first discuss possible origins for the differing values of dT_c/dP for MgB_2 reported in the literature (see Table 1). Tissen et al. [41] and, somewhat later, Lorenz et al. [43] have presented data indicating a strong inverse correlation between the magnitude of the initial slope dT_c/dP and the value of T_c at ambient pressure, i.e. $|dT_c/dP|_0$ is larger if $T_c(0)$ is smaller. To reexamine this possible correlation, we have plotted in Fig. 5 the initial slope dT_c/dP using the high-pressure data in Table 1. Taken as a whole, the data in Fig. 5 would appear to give some support to the proposed strong inverse correlation. Such a correlation is, however, *not* supported by the hydrostatic He-gas data. With the exception of the single data point of Lorenz et al. [29], all known $(dT_c/dP)_0$ values for single- or polycrystalline samples obtained using He pressure medium lie between

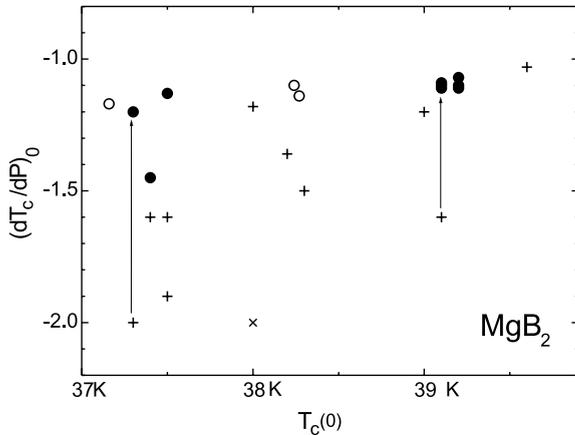


Fig. 5. Initial pressure derivative $(dT_c/dP)_0$ versus value of T_c at ambient pressure; data are taken directly from Table 1. Measurements with He (\bullet , \circ) and non-He ($+$, \times) pressure media; both polycrystalline (\bullet , $+$) and single-crystalline (\circ , \times) samples are represented. Vertical arrows show change in measured value of $(dT_c/dP)_0$ for a given sample upon changing to He pressure medium (see text).

-1.07 and -1.2 K/GPa. Although the He-gas data do not support a strong correlation between $|dT_c/dP|_0$ and $T_c(0)$, samples with lower values of $T_c(0)$ (37.16 versus 39.1 K) do appear to exhibit slightly ($\sim 5\%$) larger initial slopes dT_c/dP (-1.17 versus -1.11 K/GPa). In contrast, the $(dT_c/dP)_0$ values obtained using other less hydrostatic pressure media are often larger (up to 50–80%) in magnitude. This indicates that differences in the values of $(dT_c/dP)_0$ in the literature may depend more on the pressure medium used than on differences between samples, at least as reflected in their $T_c(0)$ values.

One way to help resolve this issue is to carry out parallel $T_c(P)$ measurements on the *same* sample using *different* pressure media. We carried out two such studies. In the first, we placed a sample provided by V. Tissen in our He-gas system, obtaining under purely hydrostatic pressure conditions $dT_c/dP \simeq -1.2$ K/GPa [44]. This value is 40% less than that (-2 K/GPa) from Tissen et al.'s DAC study [41] on the *same* sample with methanol/ethanol pressure medium (see the appropriate vertical arrow in Fig. 5). In the second experiment we took the same isotopically pure ^{11}B sample studied previously in both our He-gas and He-loaded

DAC (where $dT_c/dP \simeq -1.1$ K/GPa) and replaced the He pressure medium with Fluorinert, obtaining the DAC data shown in Fig. 4 with initial slope $dT_c/dP \simeq -1.6$ K/GPa, a nearly 50% increase in slope (see the appropriate vertical arrow in Fig. 5). Similar effects are observed with single crystals; the slope -2.0 K/GPa observed in Fluorinert [34] is much larger than that (-1.1 K/GPa) found in the present He-gas study on crystals from the same source. The large values of $|dT_c/dP|_0$ reported in the literature thus may arise from the use of fluid pressure media, such as Fluorinert or methanol/ethanol, which freeze solid at temperatures well above $T_c \approx 40$ K. The present results thus do not support the existence of the originally proposed [41,43] strong inverse correlation between $|dT_c/dP|_0$ and $T_c(0)$.

It is interesting to note that the DAC measurements of Schlachter et al. [30] with solid NaF pressure medium yield a large negative slope with increasing pressure (-1.6 K/GPa) which reduces to -1.13 K/GPa as the pressure is reduced to ambient, leaving an ambient pressure value $T_c(0)$ permanently suppressed by $\sim 12\%$ from the initial value. The authors infer that, because of shear stress effects from the solid pressure medium, the sample is degraded when pressure is applied, with no further degradation upon pressure release. It is also noteworthy that the value $dT_c/dP \simeq -1.13$ K/GPa is the same to 0.4 GPa as that obtained on the same sample in a He-gas experiment by the same group (see Table 1).

With these results in mind, it is difficult to understand the relatively small values of $|dT_c/dP|_0$ reported in the resistivity studies by Monteverde et al. [24] and Bordet et al. [42] using solid steatite pressure medium. Since their temperature-dependent resistivity data at different pressures were not published, it is difficult to speculate on possible origins for this difference. The use by these authors of the resistivity onset to define T_c could lead to substantial errors in estimating $(dT_c/dP)_0$, particularly if significant broadening occurs in the transition under pressure. We also note that in this type of pressure cell it is particularly difficult to obtain reliable resistivity data and pressure values in the lower 1–2 GPa pressure range. In these papers [24,42] no information was given whether

$T_c(P)$ was reproducible for identical samples, reversible in pressure, or whether the transition broadened significantly under pressure. We note that Struzhkin et al. [39] remeasured $T_c(P)$ in their DAC with no pressure medium whatsoever, pressing the diamond anvils directly onto the sample and gasket, and reported results resembling the two lower curves of Monteverde et al. [24]. It is also noteworthy that Razavi et al. [31] also used steatite pressure medium, and obtained the initial slope -1.03 K/GPa; in their published resistivity data there is little change in the transition width with pressure so that the estimate of the shift in T_c is relatively straightforward.

In a further experiment, we left out the pressure medium entirely and pressed two WC Bridgman anvils with 6 mm dia. flats for 5 min directly onto ~ 5 mg MgB_2 powder with 10 tons force; this typically results in a pressure distribution across the center of the disc resembling a bell-shaped curve with $P \approx 8$ GPa at the center and $P = 0$ at the edge. The sample was thoroughly compacted by this procedure, resulting in a disc-shaped sample approximately $70 \mu\text{m}$ thick. After removing the compacted disc from between the anvils, the disc was separated into three separate regions (center, middle, and outside), as seen in Fig. 6; the sample from each region was then gently broken up and

placed into our ac susceptibility coil system. As seen in Fig. 6, the sharp superconducting transition of the virgin powder sample is broadened by a significant amount (~ 10 K) by the compaction procedure, the broadening being somewhat less from the center to the middle to the outside. This broadening is presumably the result of strong plastic deformation and the resulting internal strains in the material. If strong internal strains can lead to broadening as large as 10 K at ambient pressure, it is not unreasonable to assume that such strains are capable of causing enhanced downward shifts in T_c under nonhydrostatic pressure conditions.

The important role that defects and strains play in MgB_2 's superconducting state is emphasized by the fact that the value of T_c in a large number of thin-film and bulk MgB_2 samples appears to follow a Testardi correlation [2,43]: T_c is lower for samples in which the conduction electrons are strongly scattered. Lorenz et al. [43] also report that the value of T_c is degraded with increasing lattice strain, a result confirmed by Serquis et al. [45]. T_c in MgB_2 has also been found to be lowered following mechanical milling [46] and after irradiation by fast neutrons [47]. In contrast to the work of Lorenz et al. [43] and Serquis et al. [45], Hinks et al. [38] have recently reported that accidental impurity doping can have an effect on T_c much larger than that of lattice strain. Additionally, they show that grain-interaction stresses can significantly alter the lattice parameters of MgB_2 depending on the impurity phases present with the MgB_2 . For example, the largest strains are seen for samples where MgB_4 is present as an impurity phase, imparting to the bulk sample the properties of an $\text{MgB}_2/\text{MgB}_4$ composite. One might hypothesize that grain-interaction stresses could significantly alter the response of MgB_2 grains to pressure in such samples, and, in this way, modify the observed response of T_c to pressure.

In contrast to the poor agreement between the large body of nonhydrostatic $T_c(P)$ data on MgB_2 , the agreement is remarkably good (for both single-crystalline and polycrystalline samples) between the purely hydrostatic He-gas data to 0.7 GPa and the nearly hydrostatic dense He data for $P \leq 20$ GPa (see Fig. 4). It is thus reasonable to assert that

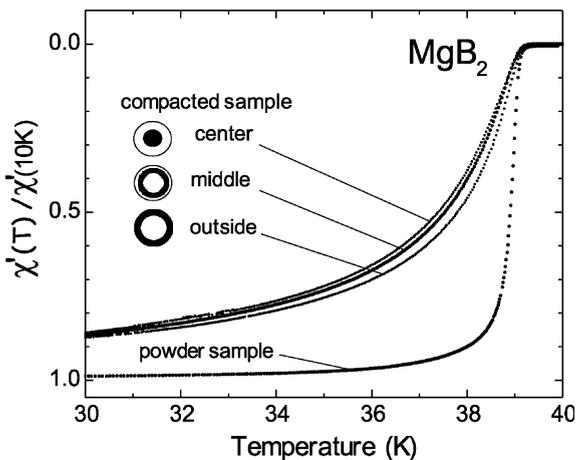


Fig. 6. Relative change in the real part of the ac susceptibility χ' of MgB_2 versus temperature for both loose powder and flat, compacted samples. For the compacted disc, samples were taken from the center, middle, and outside regions.

the intrinsic initial pressure dependence for MgB_2 samples with the highest values of T_c (39.1 K for ^{11}B) is given by $dT_c/dP \simeq -1.11(2)$ K/GPa, the $T_c(P)$ dependence to 29 GPa being given by the present single-crystal data shown in Fig. 3. We would now like to compare these experimental results with theoretical models.

4.2. Comparison with theory

For most known superconductors, including MgB_2 , T_c is found to decrease with pressure. In fact, dT_c/dP is negative for *all* simple-metal superconductors (e.g. Pb, Al, Sn, and In [48]) due to pressure-induced lattice stiffening (higher phonon frequencies) which weakens the electron–phonon coupling [23]. Rb_3C_{60} and other alkali-doped fullerenes are exceptions to this “rule”: here the rapid decrease in T_c with pressure originates not from lattice stiffening but rather from a sharp decrease in the electronic density of states $N(E_f)$ [49]. What is the origin of the negative pressure dependence of T_c for MgB_2 —is it lattice stiffening, a decrease in the electronic density of states, or something else?

Theoretical models are calculated in terms of the dependence of the relevant properties on the lattice parameters or unit cell volume V . From the intrinsic initial slope $dT_c/dP \simeq -1.11$ K/GPa for MgB_2 we can calculate the logarithmic volume derivative

$$\frac{d \ln T_c}{d \ln V} = -\frac{B}{T_c(0)} \left(\frac{dT_c}{dP} \right) = +4.18, \quad (1)$$

where we use $T_c(0) = 39.1$ K from above and the bulk modulus $B = 147.2$ GPa from He-gas neutron diffraction studies on the same sample [5].

We now convert the $T_c(P)$ data for polycrystalline MgB_2 in Fig. 4 to $T_c(V)$ data using the Murnaghan equation of state 3. In Fig. 7 we compare the resulting $T_c(V)$ dependences to that for the type “B” single-crystal from Fig. 3; the agreement is excellent considering that $T_c(0)$ for the single-crystal is nearly 1 K lower than for the polycrystalline sample.

We would now like to compare the above $T_c(V)$ dependence to the results of a theoretical calculation which takes proper account of the strong

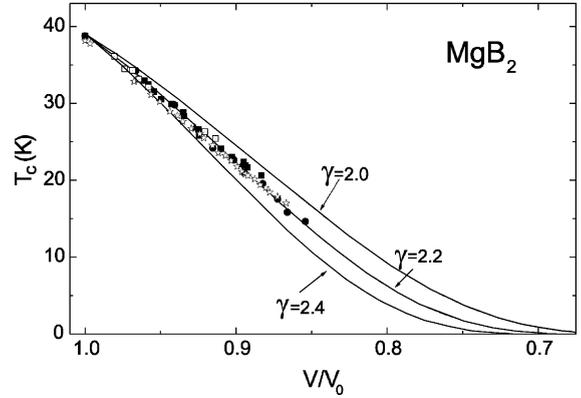


Fig. 7. T_c values from present single-crystalline (open stars) and polycrystalline (\bullet , \blacksquare , \square , \blacktriangle) data from Figs. 3 and 4 plotted versus relative volume. Solid lines are calculated curves using McMillan’s equation (Eq. (2)) for three different values of the Grüneisen parameter γ (see text).

anisotropies in the vibrational, electronic, and superconducting properties of MgB_2 , as well as the anharmonicity of the important E_{2g} phonon modes [13]. Since such a calculation as a function of the lattice parameters has yet to be carried out, we attempt in Fig. 7 a fit to the data using the well known McMillan formula [50]

$$T_c \simeq \frac{\langle \omega \rangle}{1.2} \exp \left\{ \frac{-1.04(1 + \lambda)}{\lambda - \mu^*(1 + 0.62\lambda)} \right\}, \quad (2)$$

which is valid for strong coupling ($\lambda \lesssim 1.5$) and connects the value of T_c with the electron–phonon coupling parameter λ , an average phonon frequency $\langle \omega \rangle$, and the Coulomb repulsion μ^* . However, we should not expect too much from this fit since the McMillan formula is a solution of the *isotropic* Eliashberg equations and thus ignores the strongly anisotropic nature of MgB_2 . In the following we draw heavily on the detailed analysis of Chen et al. [51] who consider the effect of pressure on the three relevant parameters in Eq. (2) $\langle \omega \rangle$, λ , and μ^* .

Taking the logarithmic volume derivative of both sides of Eq. (2), we obtain the simple relation

$$\frac{d \ln T_c}{d \ln V} = -\gamma - A_1 \left\{ \frac{\partial \ln \mu^*}{\partial \ln V} \right\} + A_2 \left\{ \frac{\partial \ln \eta}{\partial \ln V} + 2\gamma \right\}, \quad (3)$$

where $\gamma \equiv -\partial \ln \langle \omega \rangle / \partial \ln V$ is the Grüneisen parameter, $\eta \equiv N(E_F) \langle I^2 \rangle$ is the McMillan–Hopfield parameter given by the product of the electronic density of states and the average squared electronic matrix element, and the dimensionless prefactors are given by $A_1 = 1.04\mu^*(1+\lambda)[1+0.62\lambda]/[\lambda-\mu^*(1+0.62\lambda)]^2$ and $A_2 = 1.04\lambda[1+0.38\mu^*]/[\lambda-\mu^*(1+0.62\lambda)]^2$. Both A_1 and A_2 are calculated using the values of λ and μ^* at ambient pressure.

Eq. (3) looks rather formidable, but has a very simple interpretation. Fortunately, the first two terms on the right are usually small relative to the third term, as we will see below, so that $d \ln T_c / d \ln V \approx A_2 \{\partial \ln \eta / \partial \ln V + 2\gamma\}$. Since A_2 is always positive, the sign of the logarithmic derivative $d \ln T_c / d \ln V$ is determined by the relative magnitude of the two terms $\partial \ln \eta / \partial \ln V$ and 2γ . The first “electronic” term is negative ($\partial \ln \eta / \partial \ln V \approx -1$ for simple metals (s, p electrons) [23], but may equal -3 to -4 for transition metals (d electrons) [52]), whereas the second “lattice” term is positive (typically $2\gamma \approx 3-5$). Since in simple-metal superconductors, like Al, In, Sn, and Pb, the lattice term dominates over the electronic term, the sign of $d \ln T_c / d \ln V$ is the same as that of $\{\partial \ln \eta / \partial \ln V + 2\gamma\}$, namely positive; this accounts for the universal decrease of T_c with pressure due to lattice stiffening in simple metals. In selected transition metals, the electronic term may become larger than the lattice term, in which case T_c would be expected to increase with pressure, as observed in experiment [52].

We now apply the McMillan equation to the above results on MgB₂ using at ambient pressure the logarithmically averaged phonon energy from inelastic neutron studies [53] $\langle \omega \rangle = 670$ K, $T_c(0) \simeq 39.1$ K, and $\mu^* = 0.1$ [54], yielding $\lambda \simeq 0.898$, $A_1 = 0.558$ and $A_2 = 1.76$. From the expression derived by Chen et al. [51] for s, p metals $\partial \ln \eta / \partial \ln V = -[\partial \ln N(E_F) / \partial \ln V] - 2/3$ and the value $\partial \ln N(E_F) / \partial \ln V = +0.46$ from Loa and Syassen [55], the dependence of the Hopfield parameter is estimated to be $\partial \ln \eta / \partial \ln V = -1.13$, a value reasonably close to the generic value (-1) used above in the analysis for the simple-metal superconductors and to the value (-0.81) obtained from first-principles electronic structure calculations on MgB₂ by Medvedera et al. [56]. Chen

et al. [51] find that μ^* increases only weakly with pressure at a rate $\phi \equiv \partial \ln \mu^* / \partial \ln V = -0.1\gamma - 0.035$; note that this derivative is very small (~ -0.3) so that the second term on the right side of Eq. (3) is relatively unimportant. We now have estimates of all quantities on the right side of Eq. (3) except γ which we use as a fit parameter. Setting the left side of Eq. (3) equal to the experimental value $+4.18$ from Eq. (1), we find $\gamma = 2.39$, in reasonable agreement with the value $\gamma \approx 2.9$ from Raman spectroscopy studies [57] or $\gamma \approx 2.3$ from ab initio electronic structure calculations on MgB₂ [58]. Note that for the present “type B” crystal $T_c(0) \simeq 38.24$ K and $dT_c/dP \simeq -1.10$ K/GPa which gives $d \ln T_c / d \ln V = +4.23$, $\lambda \simeq 0.887$, and $\gamma = 2.36$.

Eq. (3) is only valid for small changes in the parameters, i.e. for experiments to a few GPa pressure where the change in unit cell volume is only a few percent. To attempt to fit the very high pressure $T_c(V)$ data in Figs. 3 and 7, we need to use the full McMillan equation and insert explicitly the change in the parameters with relative volume. As suggested by Chen et al. [51], we set

$$\begin{aligned} \langle \omega \rangle &= \langle \omega \rangle_0 (V/V_0)^{-\gamma}, & \lambda &= \lambda_0 (V/V_0)^\rho & \text{and} \\ \mu^* &= \mu_0^* (V/V_0)^\phi, \end{aligned} \quad (4)$$

where $\phi \equiv \{\partial \ln \eta / \partial \ln V + 2\gamma\}$. Using the values of the parameters for the sample with $T_c(0) = 39.1$ K used above to fit the initial pressure dependence ($\gamma \simeq 2.4$, $\phi = -1.13 + 2 \times 2.4 = 3.67$, and $\phi = -0.1 \times 2.4 - 0.035 = -0.275$) and inserting the volume dependences from Eq. (4) into the McMillan equation, the lower solid fit curve in Fig. 7 is obtained. Note that this curve clearly lies below the data at higher pressures. A reasonably good fit to the data over the pressure range to 32 GPa ($V/V_0 = 0.855$) is found for $\gamma = 2.2$ (see Fig. 7). As with the simple s, p metal superconductors, T_c in MgB₂ appears to decrease under pressure due to lattice stiffening. Note that within this approximation T_c approaches 0 K asymptotically at very high pressures. The fit curve for $\gamma = 2.2$ is predicted to fall below 1 K for $V/V_0 = 0.73$ which corresponds to an applied pressure of 93 GPa. The fact that the experimental data can be well fit by the McMillan formula with reasonable values of the

parameters lends support to the view that MgB_2 is a BCS superconductor with moderately strong electron–phonon coupling. However, the relatively small value of the fit parameter $\gamma=2.2$ compared to experiment [57] (2.9) is cause for concern.

As discussed in Section 1, the binary compound MgB_2 is a quasi-2D system with highly anisotropic electronic and lattice properties, including multiple superconducting gaps. The above analysis of experimental data using the McMillan formula, which represents a solution to the isotropic Eliashberg equations, is a good first step but does not permit unequivocal conclusions. What is needed is an extension of the solution of the fully anisotropic Eliashberg equations [13] to reduced lattice parameters. The initial dependences $dT_c/dP \simeq -1.11(2)$ K/GPa and $d \ln T_c/d \ln V \simeq +4.18$, and the $T_c(P)$ and $T_c(V)$ data to 32 GPa in Figs. 3, 4, and 7 stand ready to provide a stringent test of such a calculation.

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